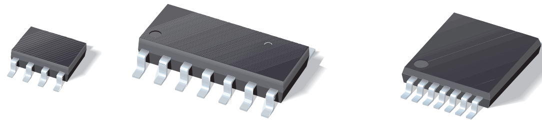


SLOS385 – SEPTEMBER 2001

LOW-NOISE, HIGH-SPEED CURRENT FEEDBACK AMPLIFIERS

FEATURES

- **Low Noise**
  - **2.9 pA/√Hz Noninverting Current Noise**
  - **10.8 pA/√Hz Inverting Current Noise**
  - **2.2 nV/√Hz Voltage Noise**
- **Wide Supply Voltage Range ±5 V to ±15 V**
- **Wide Output Swing**
  - **25 V_{PP} Output Voltage, R_L = 100 Ω, ±15-V Supply**
- **High Output Current, 150 mA (Min)**
- **High Speed**
  - **110 MHz (–3 dB, G=1, ±15 V)**
  - **1550 V/µs Slew Rate (G = 2, ±15 V)**
- **Low Distortion, G = 2**
  - **-78 dBc (1 MHz, 2 V_{PP}, 100-Ω load)**
- **Low Power Shutdown (THS3115)**
  - **300-µA Shutdown Quiescent Current Per Channel**
- **Thermal Shutdown and Short Circuit Protection**
- **Standard SOIC, SOIC PowerPAD™, and TSSOP PowerPAD™ Package**
- **Evaluation Module Available**

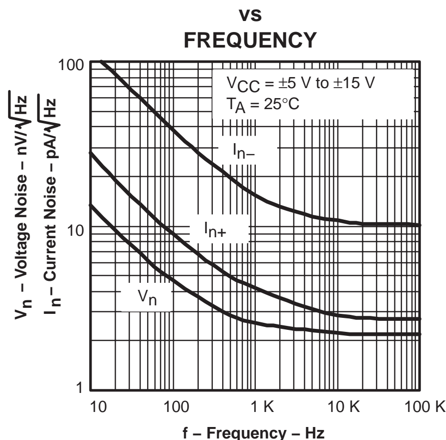
APPLICATIONS

- **Communication Equipment**
- **Video Distribution**
- **Motor Drivers**
- **Piezo Drivers**

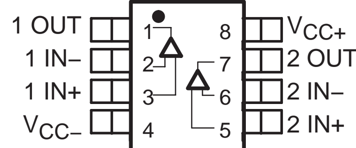
DESCRIPTION

The THS3112/5 are low-noise, high-speed current feedback amplifiers, ideal for any application requiring high output current. The low noninverting current noise of 2.9 pA/√Hz and the low inverting current noise of 10.8 pA/√Hz increase signal to noise ratios for enhanced signal resolution. The THS3112/5 can operate from ±5-V to ±15-V supply voltages, while drawing as little as 4.5 mA of supply current per channel. It offers low –78-dBc total harmonic distortion driving 2 V_{PP} into a 100-Ω load. The THS3115 features a low power shutdown mode, consuming only 300-µA shutdown quiescent current per channel. The THS3112/5 is packaged in a standard SOIC, SOIC PowerPAD™, and TSSOP PowerPAD packages.

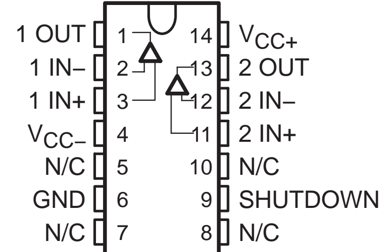
VOLTAGE NOISE AND CURRENT NOISE
vs
FREQUENCY



THS3112
SOIC (D) AND
SOIC PowerPAD™ (DDA) PACKAGE
(TOP VIEW)



THS3115
SOIC (D) AND
TSSOP PowerPAD™ (PWP) PACKAGE
(TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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AVAILABLE OPTIONS

T_A	PACKAGED DEVICE				EVALUATION MODULES
	SOIC-8 (D)	SOIC-8 PowerPAD (DDA)	SOIC-14 (D)	TSSOP-14 (PWP)	
0°C to 70°C	THS3112CD	THS3112CDDA	THS3115CD	THS3115CPWP	THS3112EVM THS3115EVM
−40°C to 85°C	THS3112ID	THS3112IDDA	THS3115ID	THS3115IPWP	

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V_{CC+} to V_{CC-} . . . . 33 V
Input voltage . . . . ± V_{CC}
Output current (see Note 1) . . . . 275 mA
Differential input voltage . . . . ± 4 V
Maximum junction temperature . . . . 150°C
Total power dissipation at (or below) 25°C free-air temperature . . . . See Dissipation Ratings Table
Operating free-air temperature, T_A: Commercial . . . . 0°C to 70°C
Industrial . . . . −40°C to 85°C
Storage temperature, T_{stg} : Commercial . . . . −65°C to 125°C
Industrial . . . . −65°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The THS3112 and THS3115 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI Technical Brief SLMA002 for more information about utilizing the PowerPAD™ thermally enhanced package.

DISSIPATION RATING TABLE

PACKAGE	θ_{JA}	T_A = 25°C POWER RATING
D-8	95°C/W‡	1.32 W
DDA	67°C/W	1.87 W
D-14	66.6°C/W‡	1.88 W
PWP	37.5°C/W	3.3 W

‡ This data was taken using the JEDEC proposed high-K test PCB. For the JEDEC low-K test PCB, the θ_{JA} is168°C/W for the D-8 package and 122.3°C/W for the D-14 package.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC+} to V_{CC-}	Dual supply	±5		±15	V
	Single supply	10		30	
Operating free-air temperature, T_A	C-suffix	0		70	°C
	I-suffix	−40		85	
Shutdown pin input levels, relative to the GND pin	High level (device shutdown)	2			V
	Low level (device active)			0.8	

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC} = ±15 V, R_F = 750 Ω, R_L = 100 Ω (unless otherwise noted)

dynamic performance

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
BW	Small-signal bandwidth (– 3 dB)	R_L = 100 Ω	R_F = 1 kΩ, G = 1	V_{CC} = ±5 V		95		MHz
				V_{CC} = ±15 V		110		
		R_L = 100 Ω	R_F = 750 Ω, G = 2	V_{CC} = ±5 V		103		
				V_{CC} = ±15 V		110		
	Bandwidth (0.1 dB)		R_F = 750 Ω, G = 2	V_{CC} = ±5 V		25		
				V_{CC} = ±15 V		48		
SR	Slew rate (see Note 2), G=8	G = 2, R_F = 680 Ω	V_O = 10 V_{PP}	V_{CC} = ±15 V		1550		V/µs
			V_O = 5 V_{PP}	V_{CC} = ±5 V		820		
				V_{CC} = ±15 V		1300		
t_s	Settling time to 0.1%	G = –1	V_O = 2 V_{PP}	V_{CC} = ±5 V		50		ns
			V_O = 5 V_{PP}	V_{CC} = ±15 V		63		

NOTE 2: Slew rate is defined from the 25% to the 75% output levels.

noise/distortion performance

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
THD	Total harmonic distortion		G = 2, R_F = 680 Ω, V_{CC} = ±15 V, f = 1 MHz	$V_{O(PP)}$ = 2 V		–78		dBc
				$V_{O(PP)}$ = 8 V		–75		
			G = 2, R_F = 680 Ω, V_{CC} = ±5 V, f = 1 MHz	$V_{O(PP)}$ = 2 V		–76		
				$V_{O(PP)}$ = 6 V		–74		
V_n	Input voltage noise		V_{CC} = ±5 V, ±15 V	f = 10 kHz		2.2		nV/√Hz
I_n	Input current noise	Noninverting Input	V_{CC} = ±5 V, ±15 V	f = 10 kHz		2.9		pA/√Hz
		Inverting Input				10.8		
	Crosstalk		G = 2, f = 1 MHz, V_O = 2 Vpp	V_{CC} = ±5 V		–67		dBc
				V_{CC} = ±15 V		–67		
	Differential gain error		G = 2, R_L = 150 Ω, 40 IRE modulation, ±100 IRE Ramp, NTSC and PAL	V_{CC} = ±5 V		0.01%		
				V_{CC} = ±15 V		0.01%		
	Differential phase error			V_{CC} = ±5 V		0.011°		
				V_{CC} = ±15 V		0.011°		

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC} = ±15 V, R_F = 750 Ω, R_L = 100 Ω (unless otherwise noted) (continued)

dc performance

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{CC} = ±5 V, V_{CC} = ±15 V	T_A = 25°C		3	8	mV
			T_A = full range			13	
	Channel offset voltage matching		T_A = 25°C		1	3	
			T_A = full range			4	
	Offset drift		T_A = full range		10		µV/°C
I_{IB}	– Input bias current	V_{CC} = ±5 V, V_{CC} = ±15 V	T_A = 25°C			23	µA
			T_A = full range			30	
	+ Input bias current		T_A = 25°C		0.33	2	
			T_A = full range			3	
	Input offset current		T_A = 25°C		4	22	
			T_A = full range			30	
Z_{OL}	Open loop transimpedance	V_{CC} = ±5 V, V_{CC} = ±15 V	R_L = 1 kΩ,		1		MΩ

input characteristics

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{ICR}	Input common-mode voltage range	V_{CC} = ±5 V	T_A = full range	±2.5	±2.7		V
		V_{CC} = ±15 V		±12.5	±12.7		
CMRR	Common-mode rejection ratio	V_{CC} = ±5 V, V_I = –2.5 V to 2.5 V	T_A = 25°C	56	62		dB
			T_A = full range	54			
		V_{CC} = ±15 V, V_I = –12.5 V to 12.5 V	T_A = 25°C	63	67		
			T_A = full range	60			
R_I	Input resistance	+ Input			1.5		MΩ
		– Input			15		Ω
C_i	Input capacitance				2		pF

output characteristics

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V_O	Output voltage swing	G = 4, V_I = 1 V, V_{CC} = ±5 V	R_L = 1 kΩ,	T_A = 25°C		3.9		V
			R_L = 100 Ω,	T_A = 25°C	3.6	3.8		
				T_A = full range	3.4			
		G = 4, V_I = 3.4 V, V_{CC} = ±15 V	R_L = 1 kΩ,	T_A = 25°C		13.5		
			R_L = 100 Ω,	T_A = 25°C	12.2	13.3		
				T_A = full range	12			
I_O	Output current drive	G = 4, V_I = 0.9 V, V_{CC} = ±5 V	R_L = 25 Ω,	T_A = 25°C	100	130		mA
		G = 4, V_I = 1.7 V, V_{CC} = ±15 V	R_L = 25 Ω,		175	270		
r_o	Output resistance	open loop				14		Ω

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC} = ±15 V, R_F = 750 Ω, R_L = 100 Ω, GND = 0 V (unless otherwise noted) (continued)

power supply

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_{CC}	Quiescent current (per amplifier)	V_{CC} = ±5 V	T_A = 25°C		4.4	5.5	mA
			T_A = full range			6	
		V_{CC} = ±15 V	T_A = 25°C		4.9	6.5	
			T_A = full range			7.5	
PSRR	Power supply rejection ratio	V_{CC} = ±5 V	T_A = 25°C	53	60		dB
			T_A = full range	50			
		V_{CC} = ±15 V	T_A = 25°C	68	74		
			T_A = full range	66			

shutdown characteristics (THS3115 only)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CC(SHDN)}$	Shutdown quiescent current (per channel)	V_{GND} = 0 V, V_{CC} = ±5 V, ±15 V		0.3	0.45	mA
t_{DIS}	Disable time (see Note 3)	V_{CC} = ±15 V		200		ns
t_{EN}	Enable time (see Note 3)	V_{CC} = ±15 V		300		ns
$I_{IL(SHDN)}$	Shutdown pin input bias current for power up	V_{CC} = ±5 V, ±15 V, $V_{(SHDN)}$ = 0 V		18	25	μA
$I_{IH(SHDN)}$	Shutdown pin input bias current for power down	V_{CC} = ±5 V, ±15 V, $V_{(SHDN)}$ = 3.3 V		110	130	μA

NOTE 3: Disable/enable time is defined as the time from when the shutdown signal is applied to the SHDN pin to when the supply current has reached half of its final value.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
	Small signal closed loop gain	vs Frequency	1 – 11, 13, 14
	Gain and phase	vs Frequency	12
	Small signal closed loop noninverting gain	vs Frequency	15, 16
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	Small and large signal output	vs Frequency	19, 20
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V_n, I_n	Voltage noise and current noise	vs Frequency	25
CMRR	Common-mode rejection ratio	vs Frequency	26
PSRR	Power supply rejection ratio	vs Frequency	27
	Crosstalk	vs Frequency	28
Z_o	Output impedance	vs Frequency	29
SR	Slew rate	vs Output voltage step	30
V_{IO}	Input offset voltage	vs Free-air temperature	31
		vs Common-mode input voltage	32
I_B	Input bias current	vs Free-air temperature	33
V_O	Output voltage	vs Output current	34, 35
	Output voltage headroom	vs Output current	36
I_{CC}	Supply current (per channel)	vs Supply voltage	37
	Shutdown response		38

TYPICAL CHARACTERISTICS

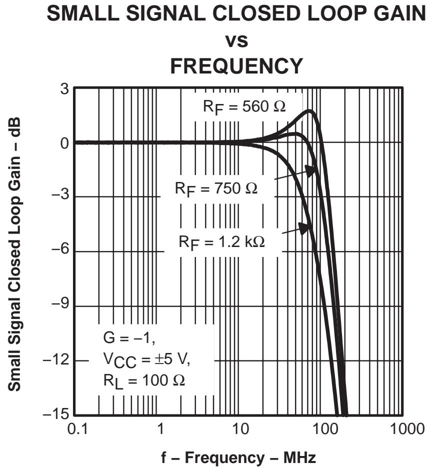


Figure 1

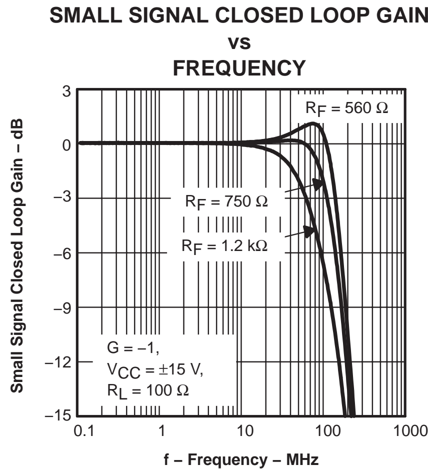


Figure 2

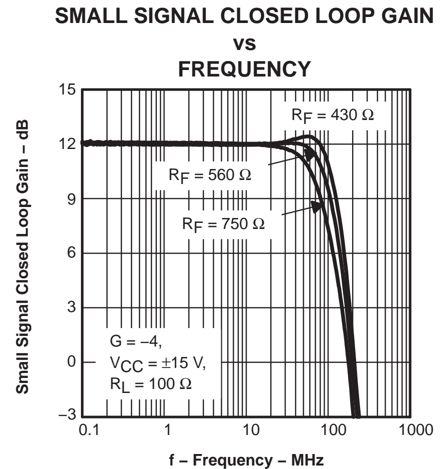
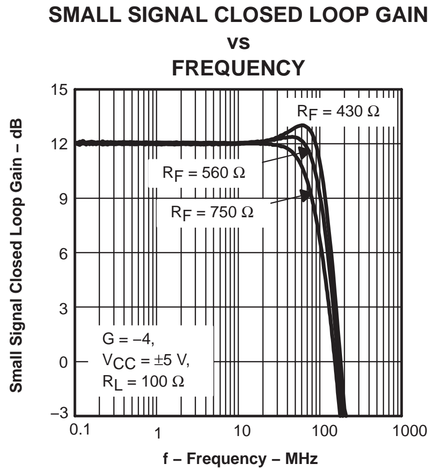


Figure 3



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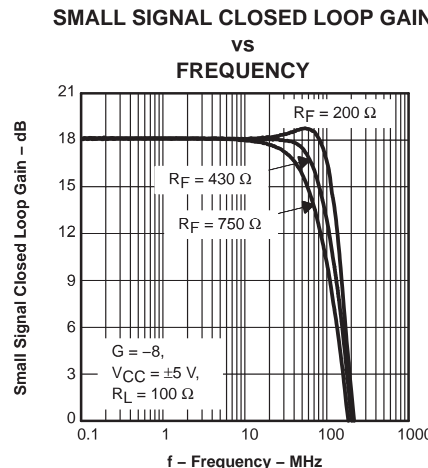

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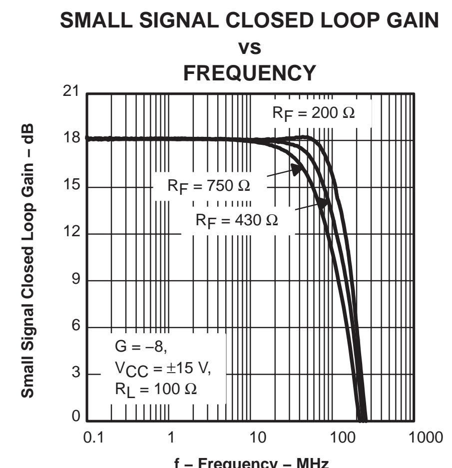

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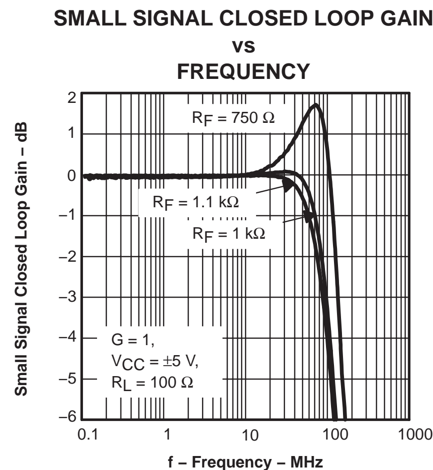

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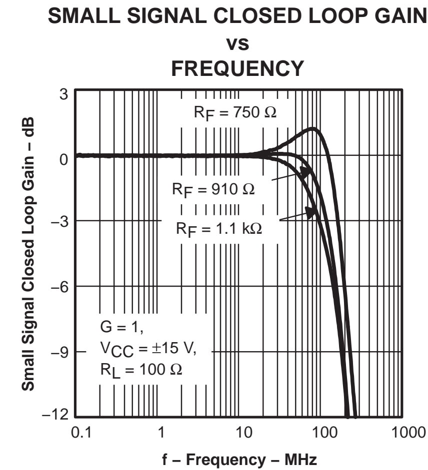

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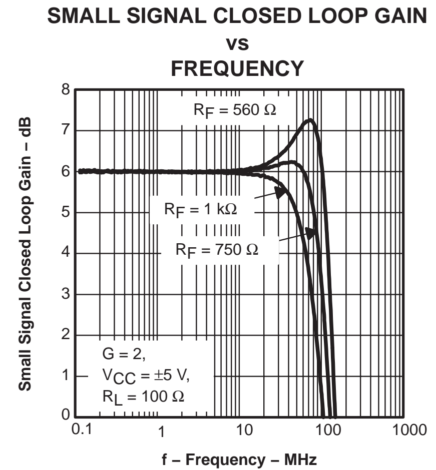
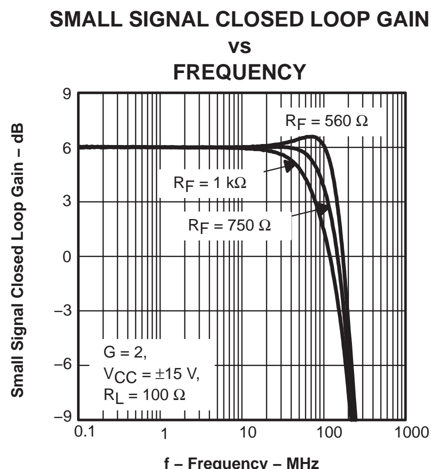


Figure 9

TYPICAL CHARACTERISTICS



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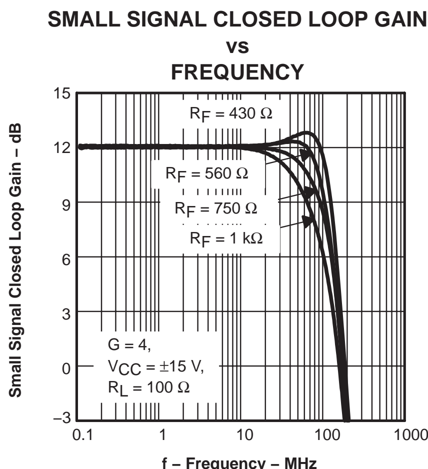

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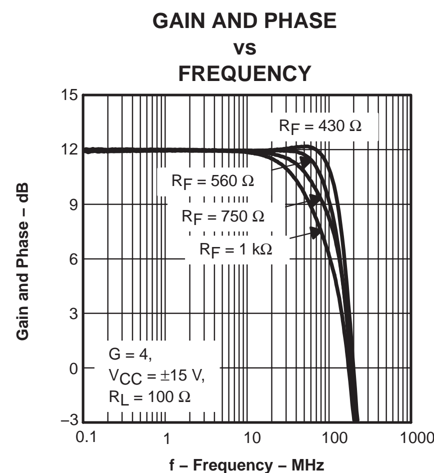

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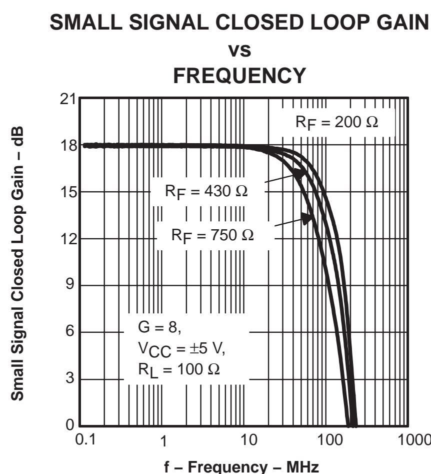


Figure 13

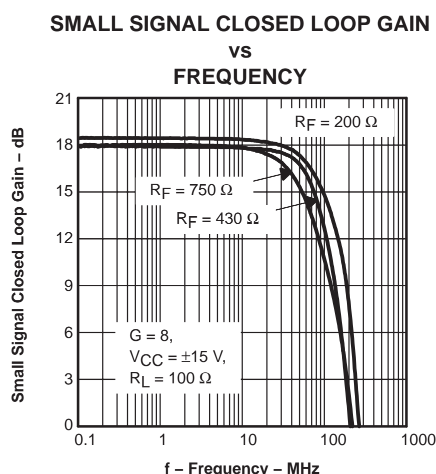
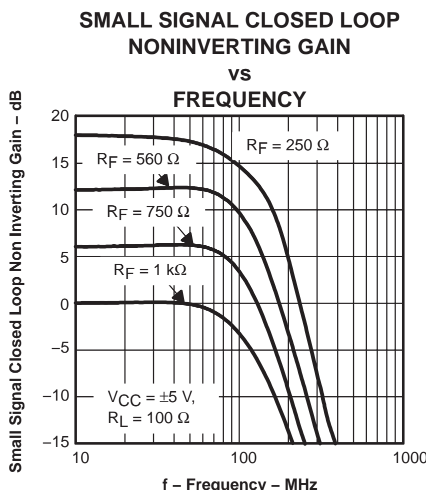


Figure 14



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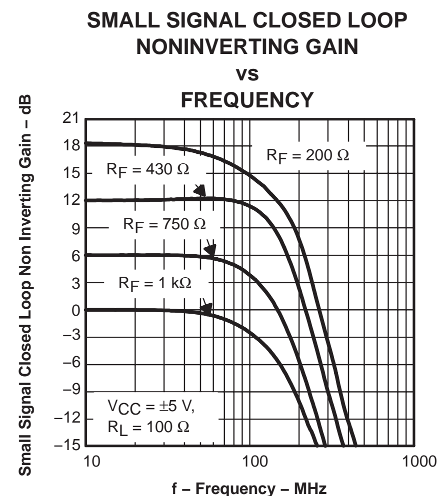

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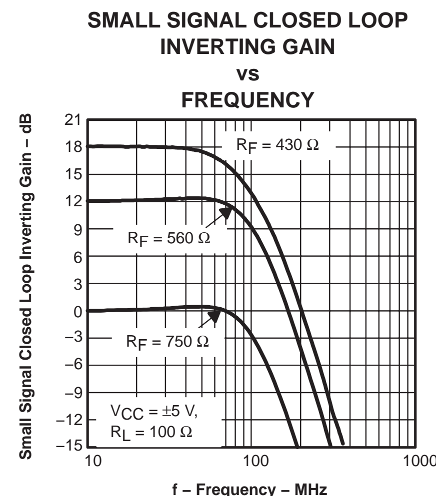

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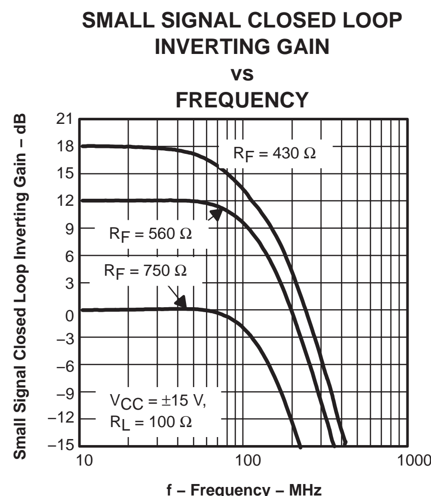
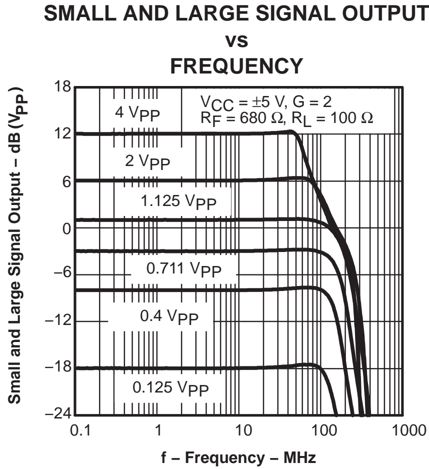


Figure 18

TYPICAL CHARACTERISTICS



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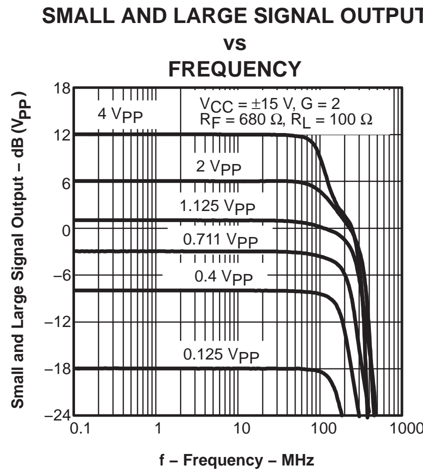

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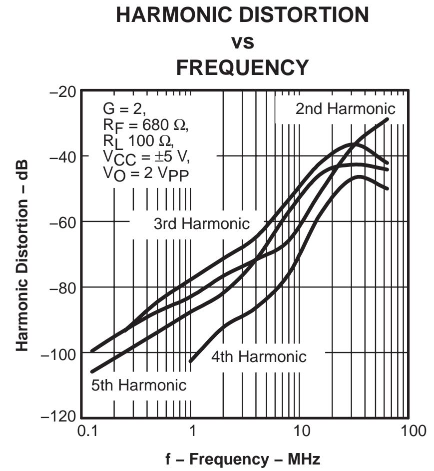

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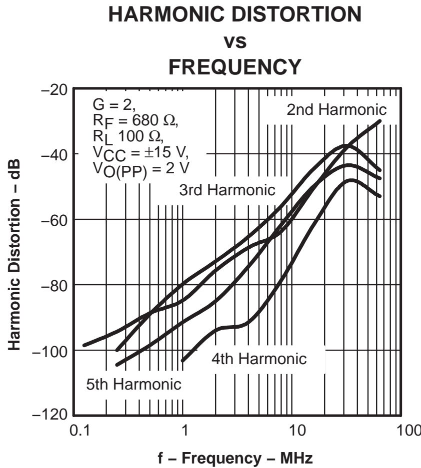

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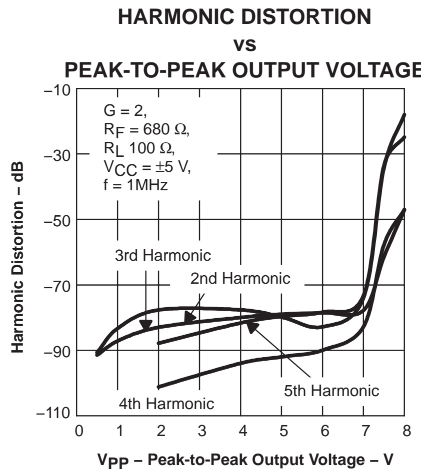

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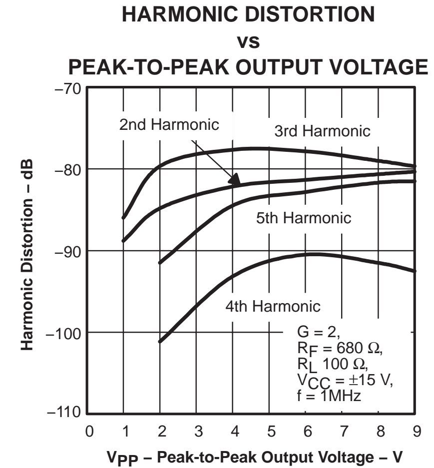

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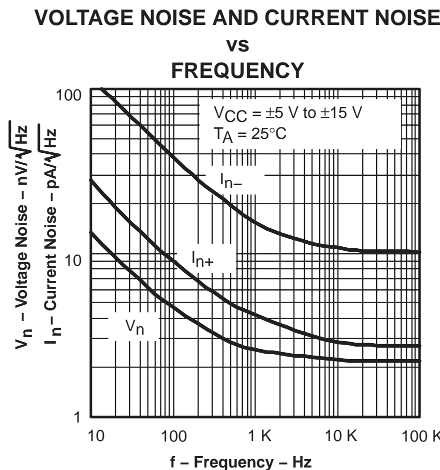

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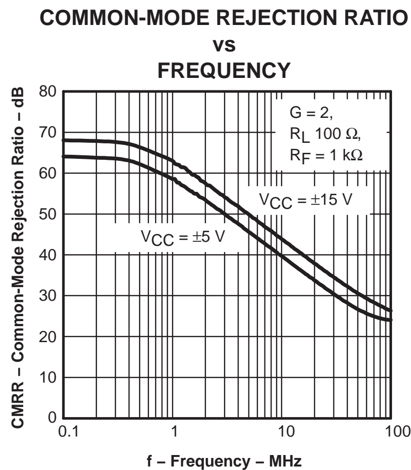

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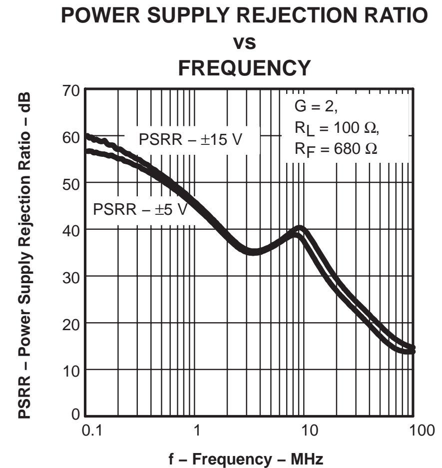


Figure 27

TYPICAL CHARACTERISTICS

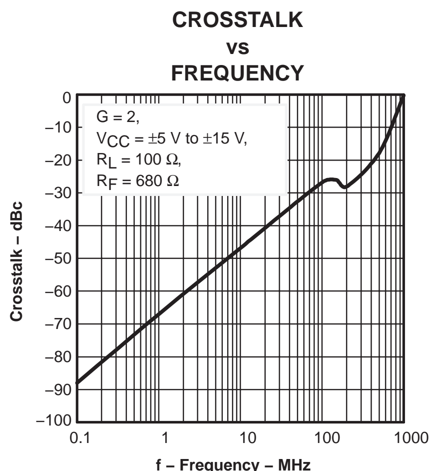
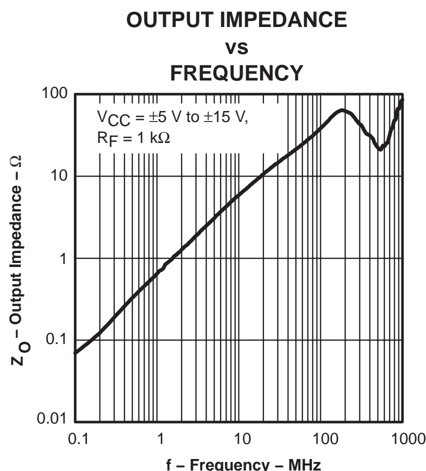


Figure 28



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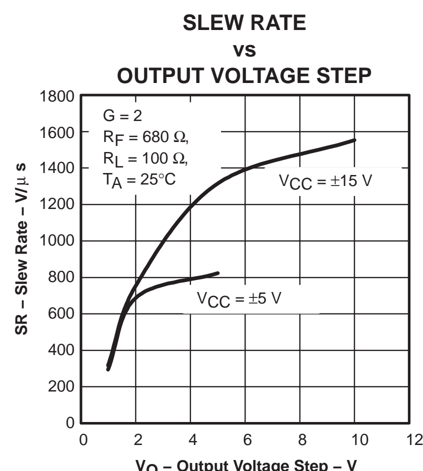

Figure 30

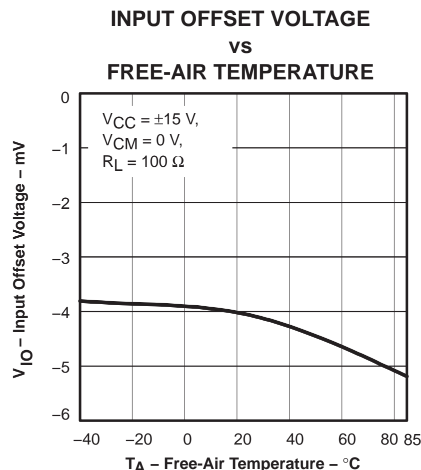

Figure 31

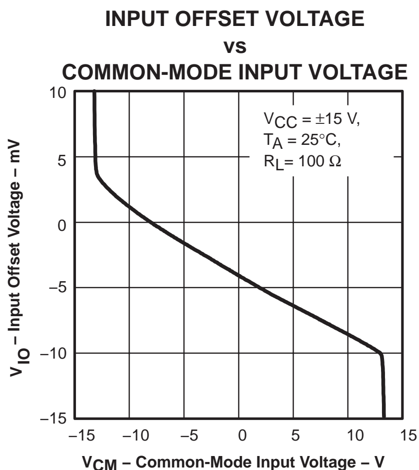

Figure 32

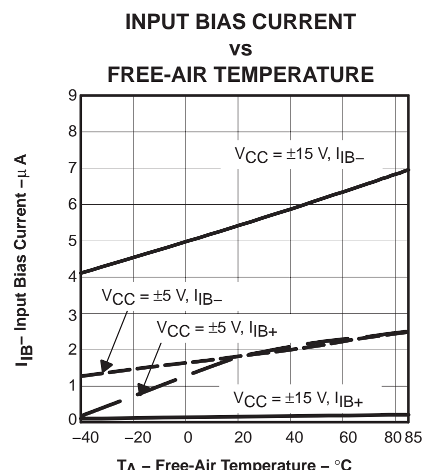

Figure 33

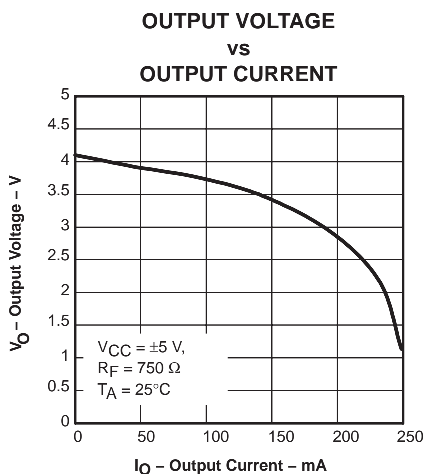

Figure 34

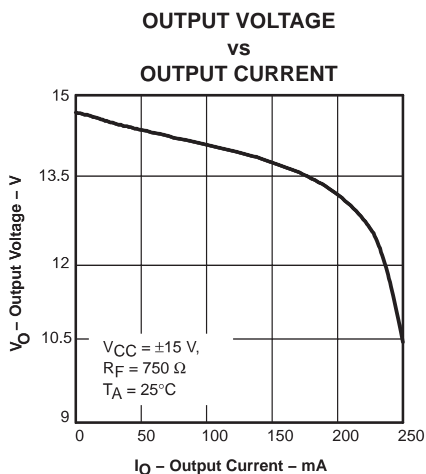

Figure 35

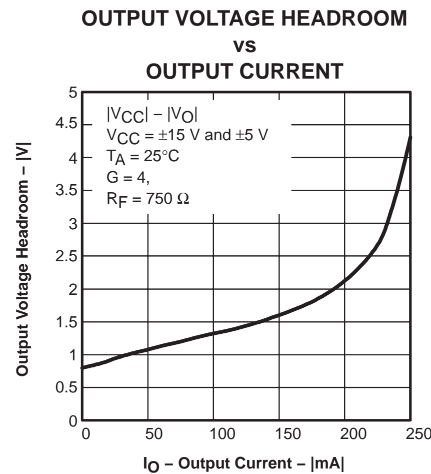

Figure 36

TYPICAL CHARACTERISTICS

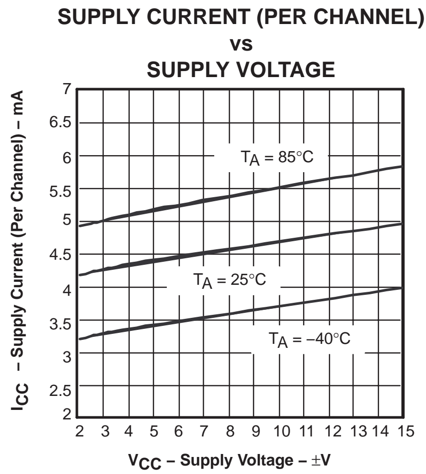

Figure 37

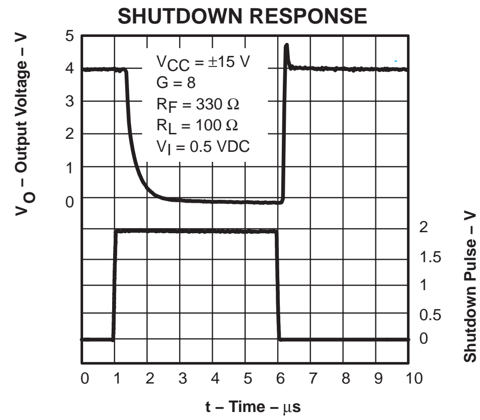

Figure 38

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
THS3112CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3112CDDA	ACTIVE	SO Power PAD	DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112CDDAG3	ACTIVE	SO Power PAD	DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112CDDAR	ACTIVE	SO Power PAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112CDDARG3	ACTIVE	SO Power PAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3112CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3112CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3112ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3112IDDA	ACTIVE	SO Power PAD	DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112IDDAG3	ACTIVE	SO Power PAD	DDA	8	75	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112IDDAR	ACTIVE	SO Power PAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112IDDARG3	ACTIVE	SO Power PAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM
THS3112IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3115CD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3115CDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3115CPWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115CPWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115CPWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115CPWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
THS3115IDG4	ACTIVE	SOIC	D	14	50	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
						no Sb/Br)		
THS3115IPWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115IPWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115IPWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
THS3115IPWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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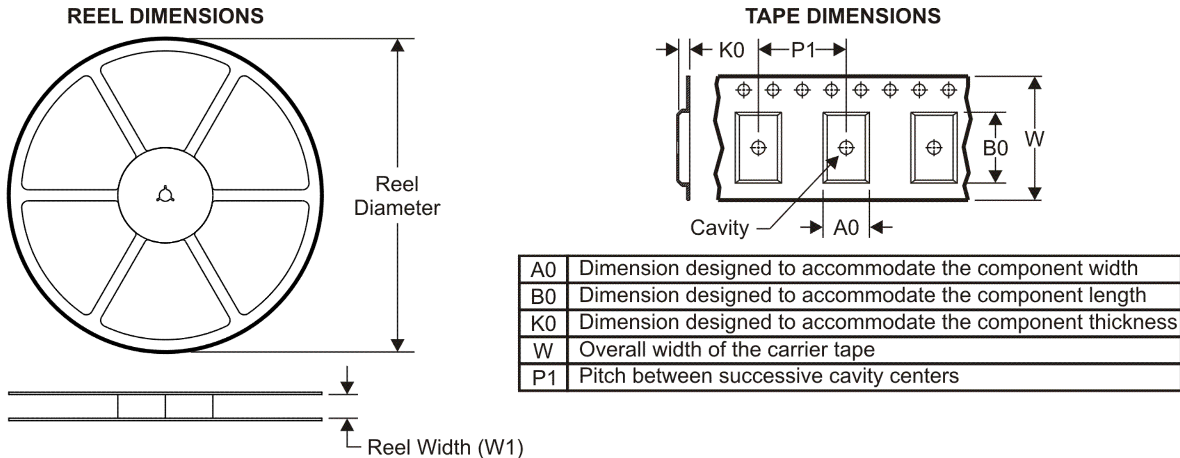
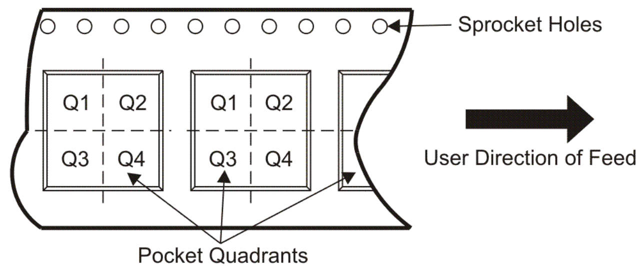


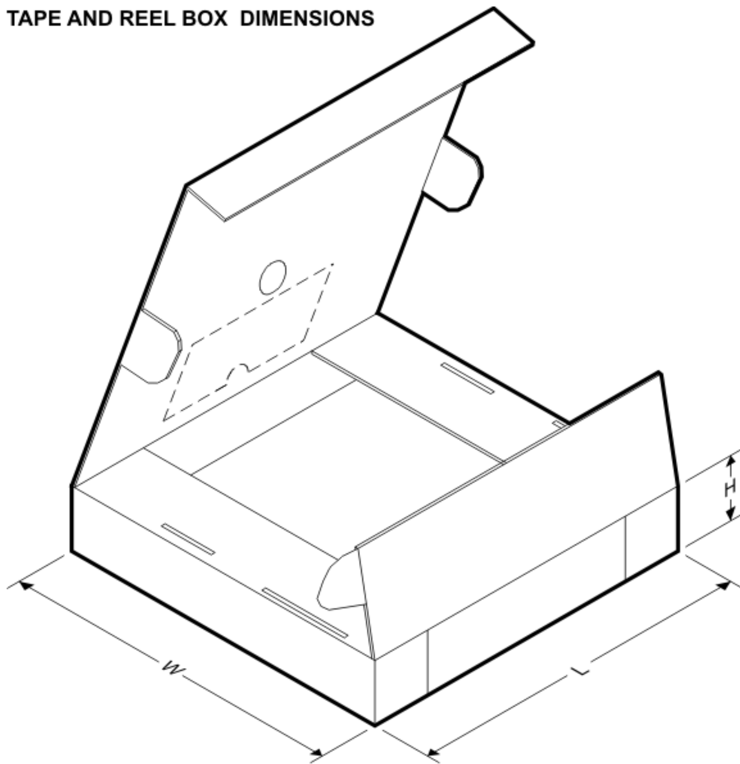
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS3112CDDAR	SO Power PAD	DDA	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS3112CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS3112IDDAR	SO Power PAD	DDA	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS3115CPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.67	5.4	1.6	8.0	12.0	Q1
THS3115IPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.67	5.4	1.6	8.0	12.0	Q1

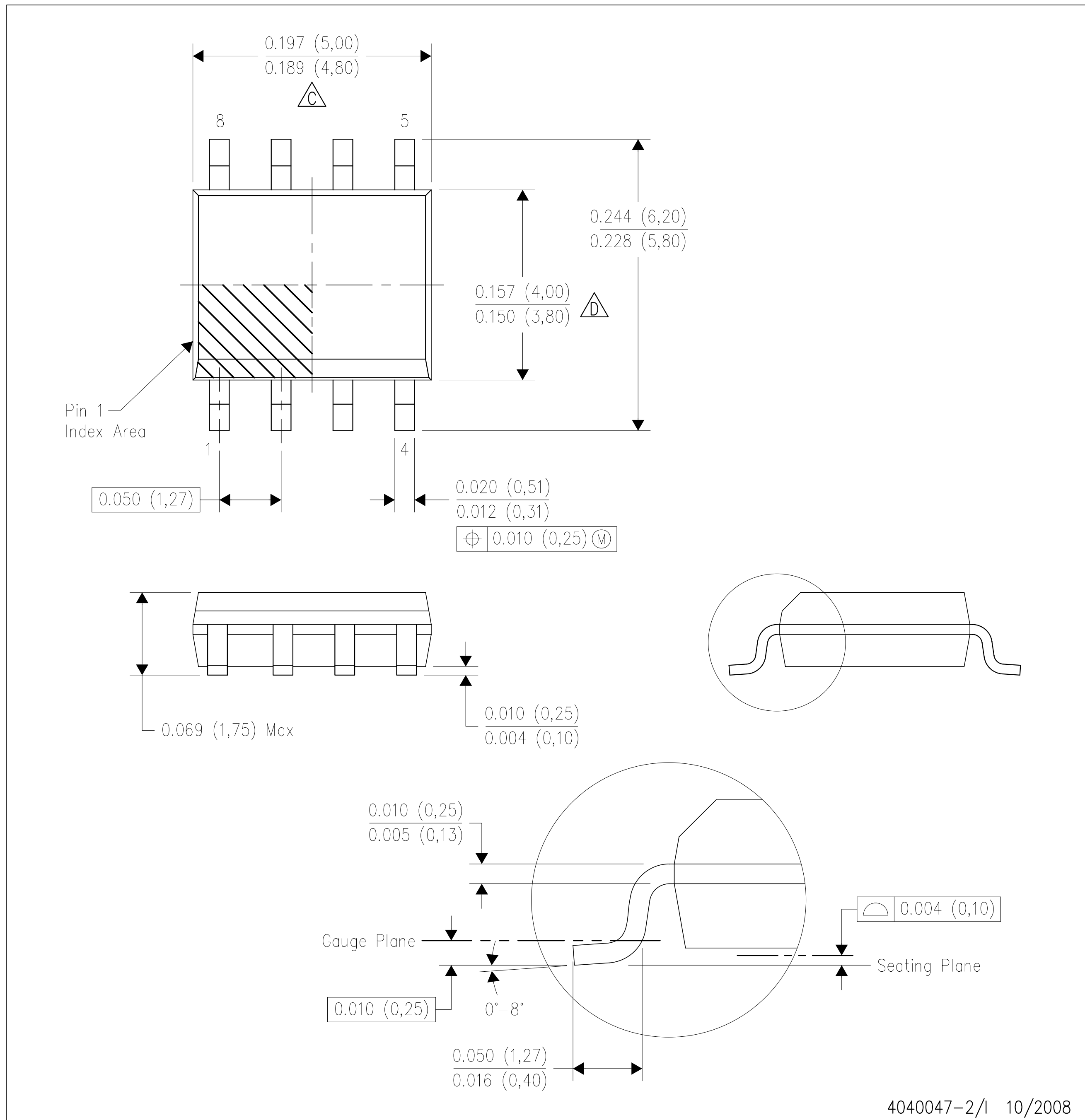
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

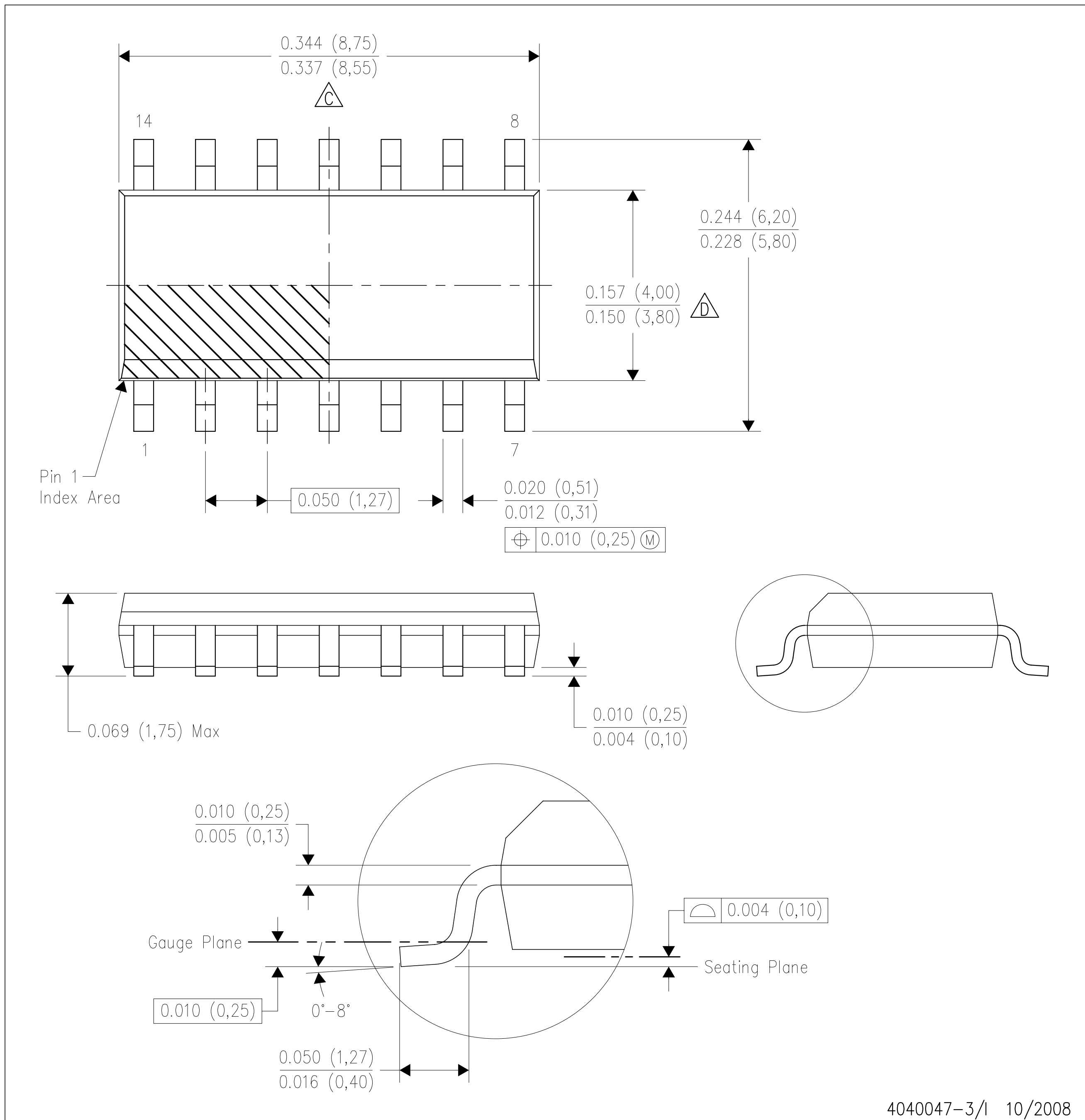
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS3112CDDAR	SO PowerPAD	DDA	8	2500	346.0	346.0	29.0
THS3112CDR	SOIC	D	8	2500	346.0	346.0	29.0
THS3112IDDAR	SO PowerPAD	DDA	8	2500	346.0	346.0	29.0
THS3115CPWPR	HTSSOP	PWP	14	2000	346.0	346.0	29.0
THS3115IPWPR	HTSSOP	PWP	14	2000	346.0	346.0	29.0

D (R–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



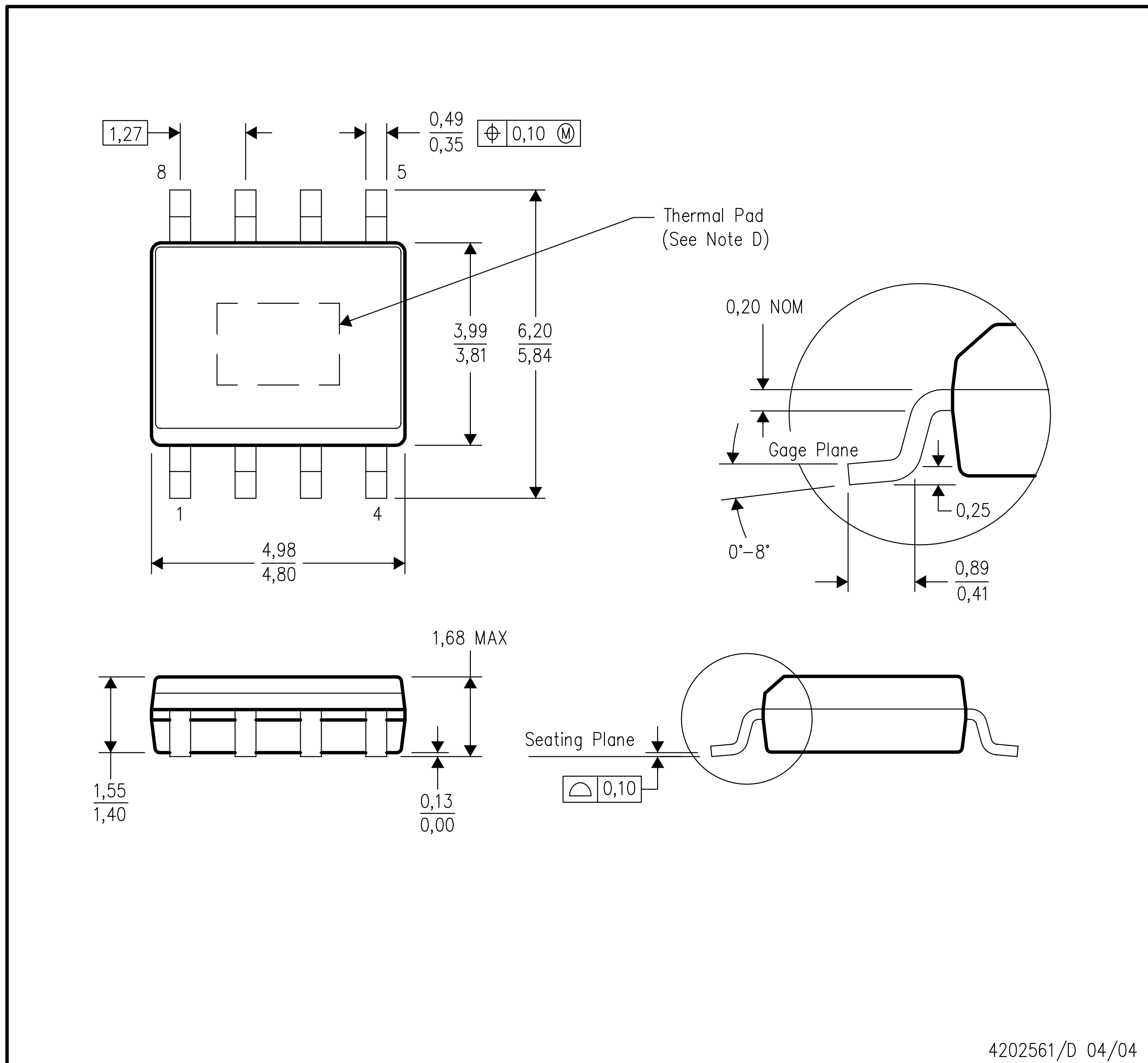
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
E. Reference JEDEC MS-012 variation AA.

D (R–PDSO–G14) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
E. Reference JEDEC MS-012 variation AB.

DDA (R-PDSO-G8) PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http: //www.ti.com>.

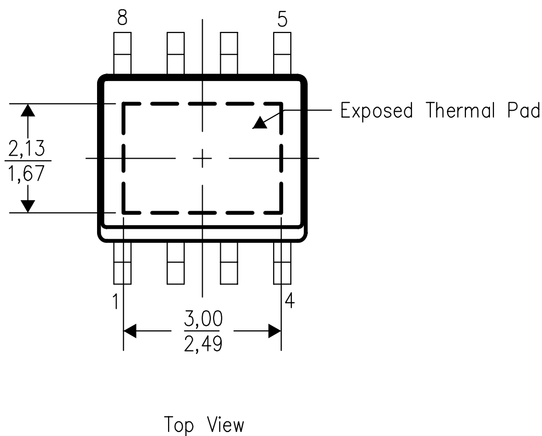
PowerPAD is a trademark of Texas Instruments.

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

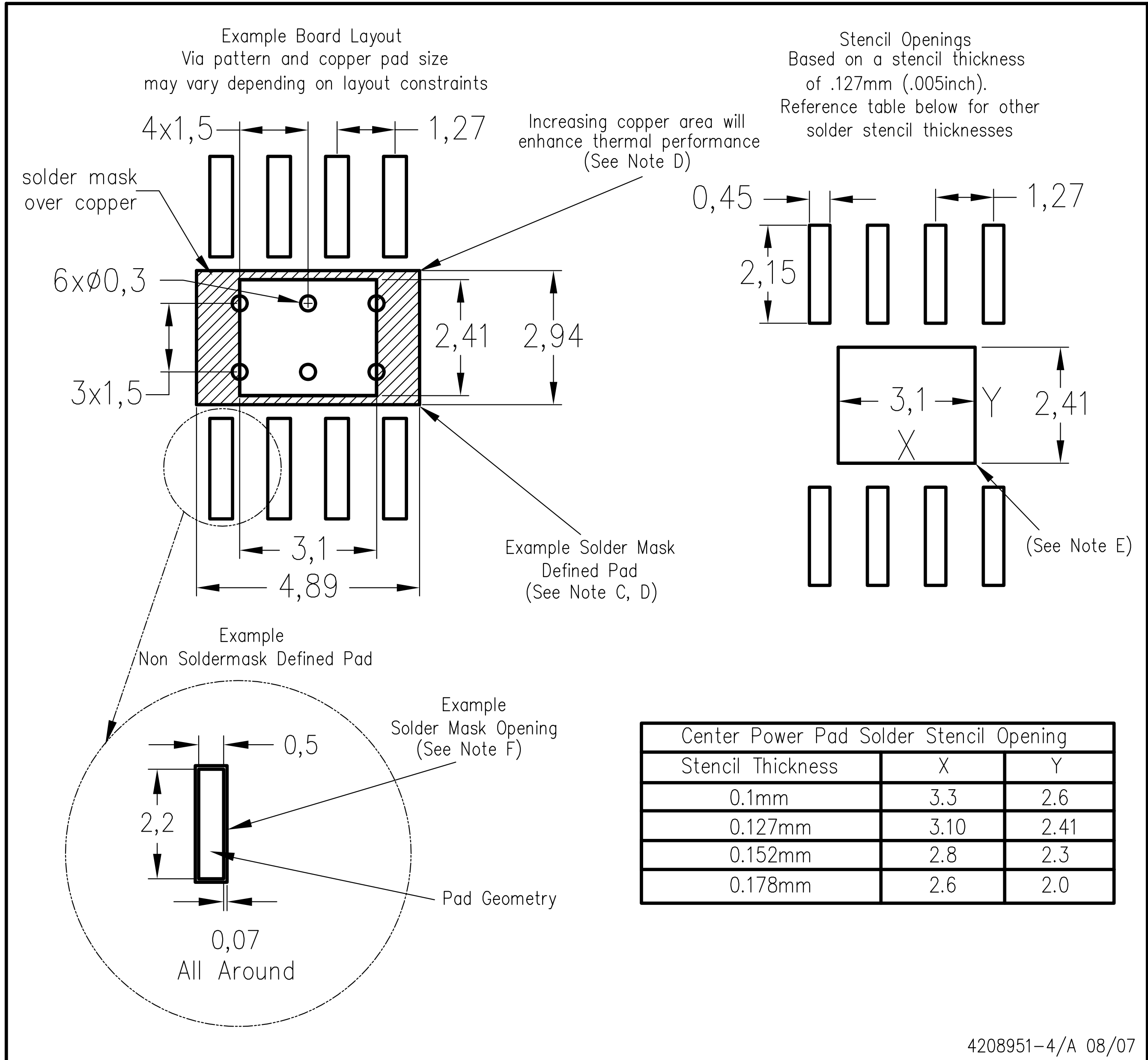


Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

DDA (R-PDSO-G8) PowerPAD™



Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	3.3	2.6
0.127mm	3.10	2.41
0.152mm	2.8	2.3
0.178mm	2.6	2.0

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http: //www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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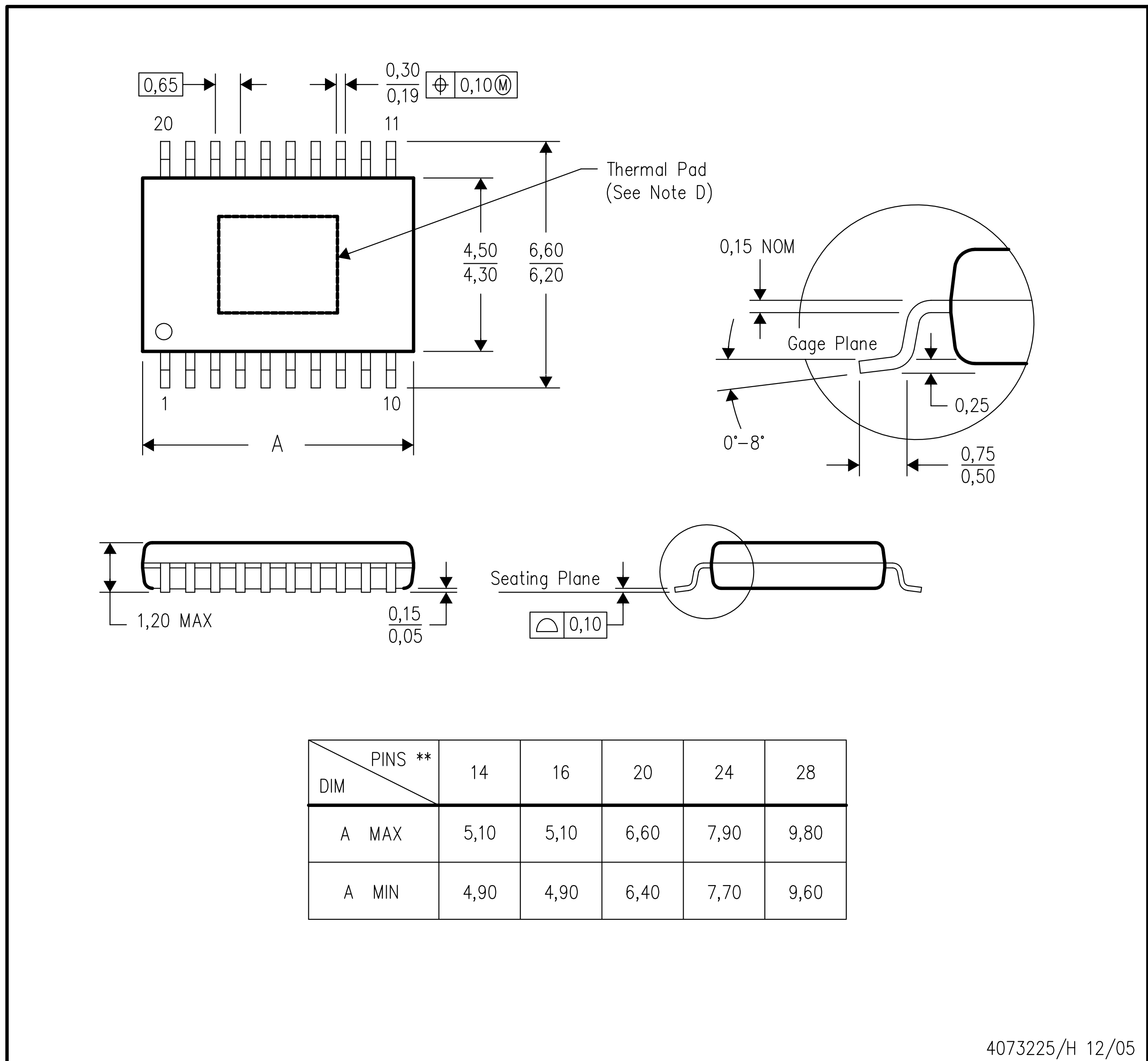
PWP (R-PDSO-G**) PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

20 PIN SHOWN



DIM \ PINS **	14	16	20	24	28
A MAX	5,10	5,10	6,60	7,90	9,80
A MIN	4,90	4,90	6,40	7,70	9,60

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
- E. Falls within JEDEC MO-153

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THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

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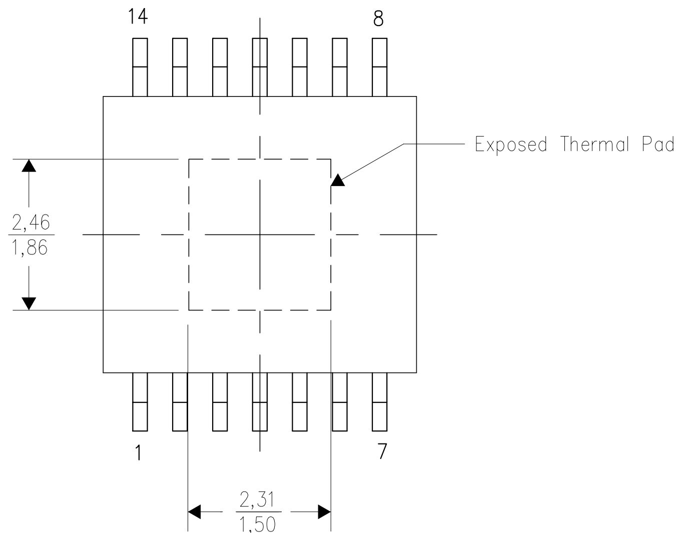
The exposed thermal pad dimensions for this package are shown in the following illustration.

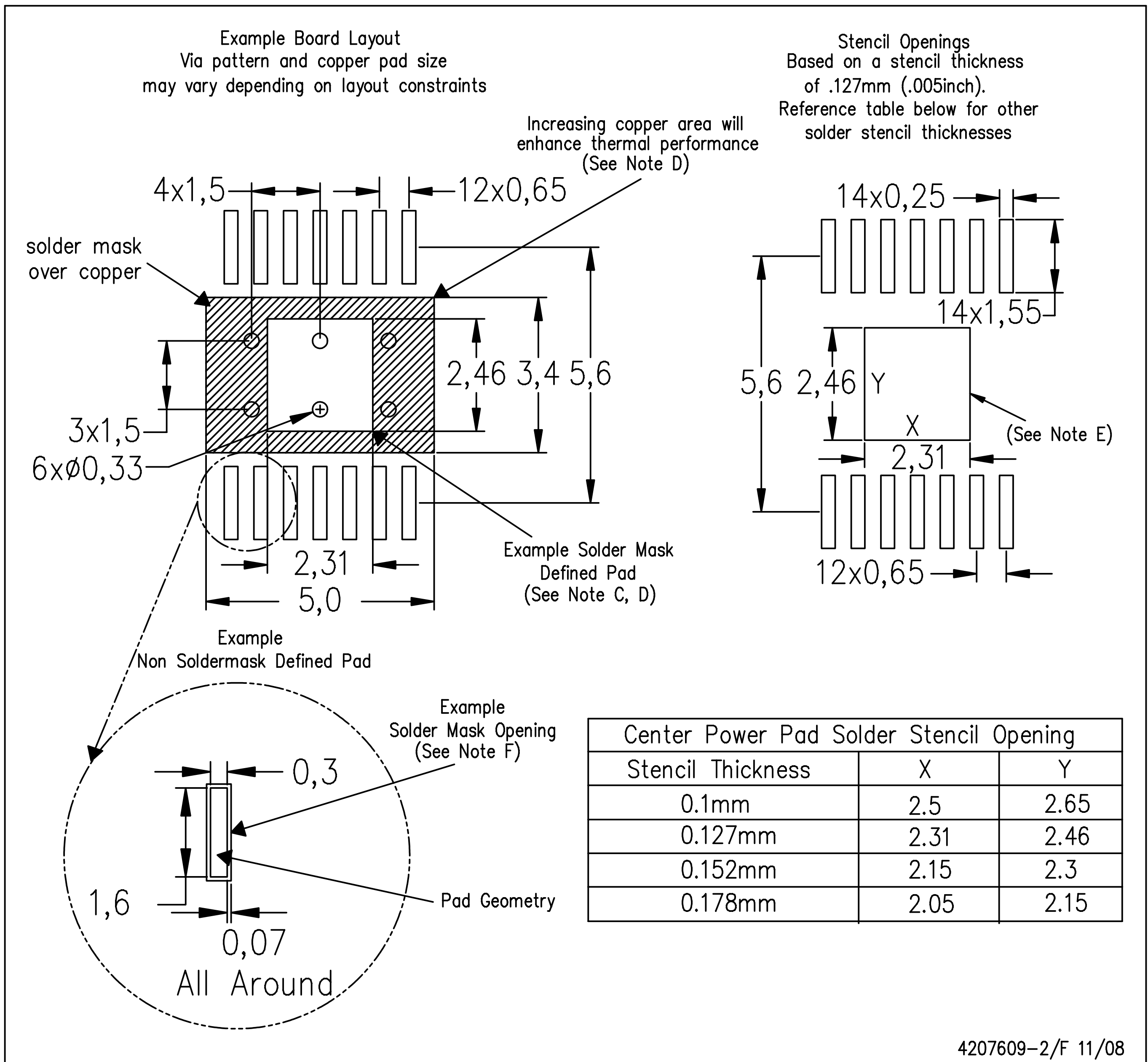


Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

PWP (R-PDSO-G14) PowerPAD™



Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.5	2.65
0.127mm	2.31	2.46
0.152mm	2.15	2.3
0.178mm	2.05	2.15

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

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